

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

BFL4001 — General-Purpose Switching Device Applications

Features

- ON-resistance RDS(on)= 2.1Ω (typ.)
- 10V drive

• Input capacitance Ciss=850pF (typ.)

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		900	V
Gate-to-Source Voltage	V _{GSS}		±30	V
D. (1.0)	I _{Dc} *1	Limited only by maximum temperature Tch=150°C	6.5	А
Drain Current (DC)	I _{Dpack} *2	Tc=25°C (SANYO's ideal heat dissipation condition)*3	4.1	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	13	А
Allowable Power Dissipation	D-		2.0	W
	PD	Tc=25°C (SANYO's ideal heat dissipation condition)*3	37	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Energy (Single Pulse) *4	EAS		223	mJ
Avalanche Current *5	IAV		6.5	А

Note: *1 Shows chip capability

The method is applying silicone grease to the backside of the device and attaching the device to water-cooled radiator made of aluminium.

Package Dimensions

unit : mm (typ) 7528-001

10.16 ## 2.54 ## 2.54 ## BFL4001-1E ## 2.54 ## 2.54 ## 3.18 ## 3.

Product & Package Information

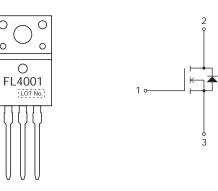
• Package : TO-220F-3FS

• JEITA, JEDEC : SC-67

• Minimum Packing Quantity : 50 pcs./magazine

Marking

Electrical Connection



SANYO Semiconductor Co., Ltd.

http://semicon.sanyo.com/en/network

^{*2} Package limited

^{*3} SANYO's condition is radiation from backside.

^{*4} VDD=50V, L=10mH, IAV=6.5A

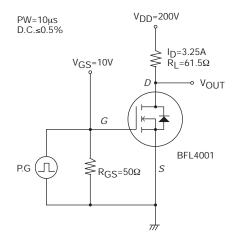
^{*5} L≤10mH, single pulse

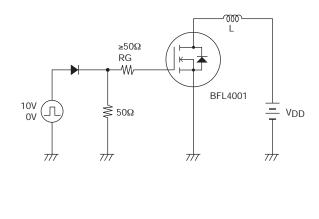
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit
Parameter	Symbol	Conditions	min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=10mA, VGS=0V	900			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =720V, V _{GS} =0V			1.0	mA
Gate-to-Source Leakage Current	IGSS	V _{GS} =±30V, V _{DS} =0V			±100	nA
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	2.0		4.0	V
Forward Transfer Admittance	yfs	VDS=20V, ID=3.25A	1.8	3.6		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)	I _D =3.25A, V _G S=10V		2.1	2.7	Ω
Input Capacitance	Ciss			850		pF
Output Capacitance	Coss	V _{DS} =30V, f=1MHz		130		pF
Reverse Transfer Capacitance	Crss			43		pF
Turn-ON Delay Time	t _d (on)			19		ns
Rise Time	t _r	Con appointed Toot Circuit		49		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		156		ns
Fall Time	tf			52		ns
Total Gate Charge	Qg			44		nC
Gate-to-Source Charge	Qgs	V _{DS} =200V, V _{GS} =10V, I _D =6.5A		7.0		nC
Gate-to-Drain "Miller" Charge	Qgd			22		nC
Diode Forward Voltage	V _{SD}	I _S =6.5A, V _{GS} =0V		0.85	1.2	V

Switching Time Test Circuit

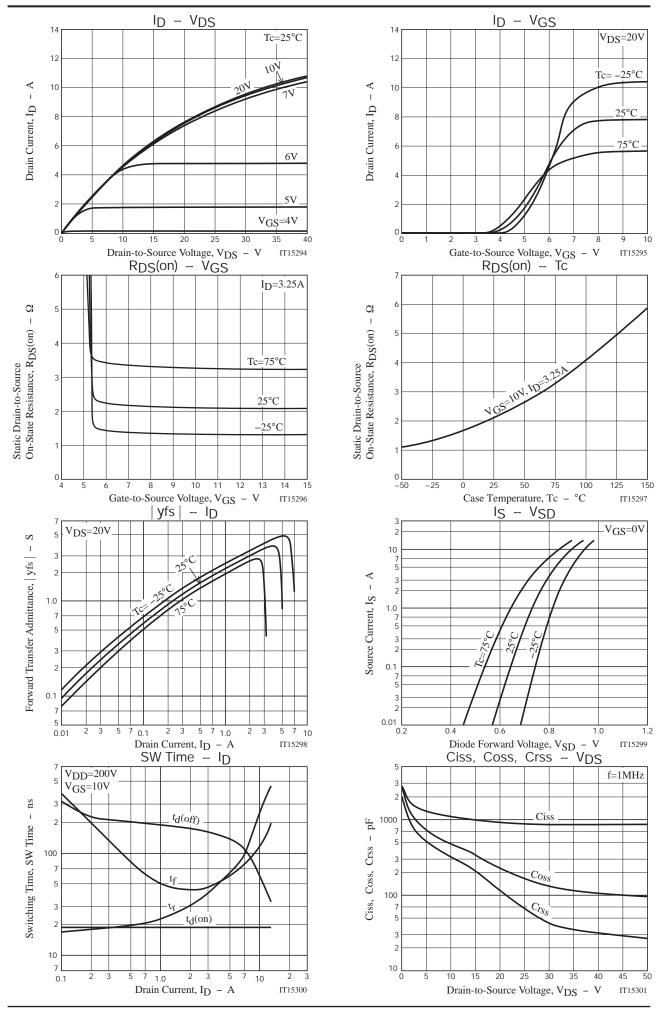
Avalanche Resistance Test Circuit

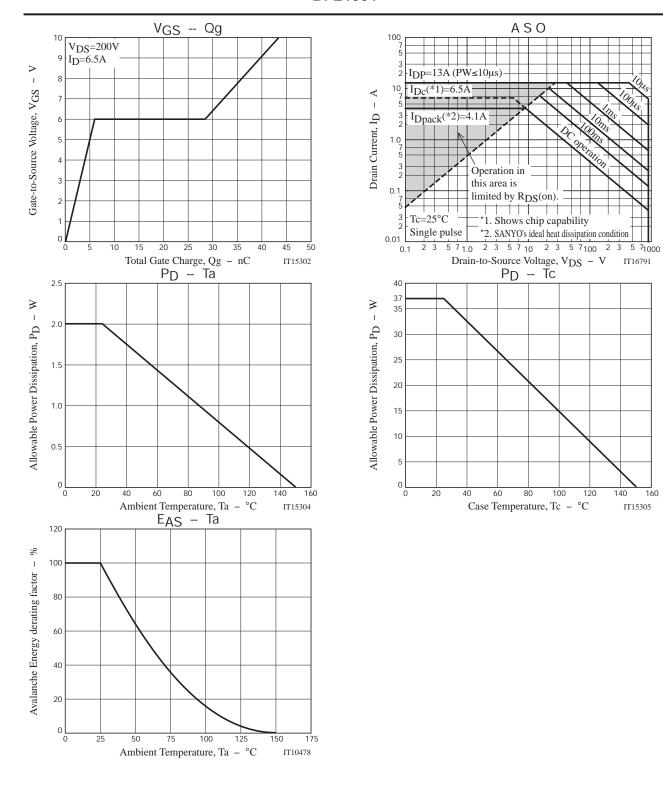




Ordering Information

Device	Package	Shipping	memo
BFL4001-1E	TO-220F-3FS	50pcs./magazine	Pb Free





140

160

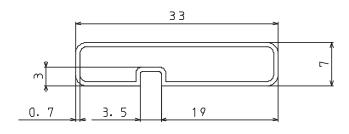
IT15305

Magazine Specification

BFL4001-1E

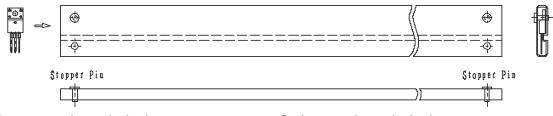
1. Packing Format

Package Name	Magazine Name	Maximum Number of devices contained (pcs			Packing format		
1 4 4 4 6 4 1 (4 4 4 4	Idagas ing Hams	I	Inner box	Outer box	Inner BOX	Outer BOX	
TO-220F-3F\$	TO-220F	50	1, 000	4,000	SPD-0V0001 20 magazines contained Dimensions:mm (external) 568×150×55	SPT-081029 4 inner boxes contained Dimensions:mm (external) 590×225×178	

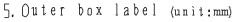


Tolerance=±0, 3mm
Thickness=0, 7±0, 2mm
Length =532, 5±2mm
Material =PVC (Antistatic treatment)

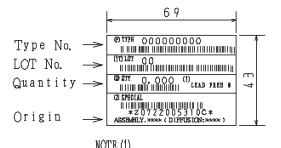
3. Storage method to magazine

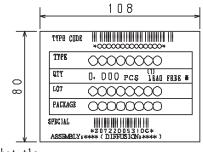


4. Inner box label (unit:mm)



It is a label at the time of factory shigments. The form of a label may change in physical distribution process.



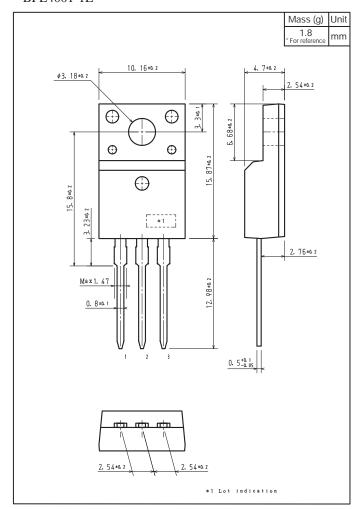


The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

Label		JEITA Phase
LEAD FREE	3	JEITA Phase 3A

Outline Drawing

BFL4001-1E



Note on usage: Since the BFL4001 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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